

## HMC466LP4E

Data Sheet

MMIC VCO w/ BUFFER AMPLIFIER, 6.1

Manufacturers Analog Devices, Inc

Package/Case QFN-24

Product Type RF Integrated Circuits

RoHS Pb-free Halide free

Lifecycle



Images are for reference only

Please submit RFQ for HMC466LP4E or <a href="mailto:Em

**RFO** 

## **General Description**

The HMC466LP4(E) is a GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCO with an integrated resonator, negative resistance device, varactor diode, and buffer amplifier. Covering 6.1 to 6.72 GHz, the VCO's phase noise performance is excellent over temperature, shock, vibration and process due to the oscillator's monolithic structure. Power output is 4.5 dBm typical from a single supply of 3V @ 31mA. The voltage controlled oscillator is packaged in a low cost leadless QFN 4x4 mm surface mount package.

## Features Application

Pout: +4.5 dBm VSAT & Microwave Radio

Phase Noise: -101 dBc/Hz @100 KHz CATV & Broadcast Relays

No External Resonator Needed Test Equipment & Industrial Controls

Single Supply: +3V @ 31 mA Military

QFN Leadless SMT Package, 16 mm<sup>2</sup>



## **Related Products**



HMC3653LP3BE
Analog Devices, Inc
QFN-12



HMC253AQS24
Analog Devices, Inc
24-SSOP (0.154, 3.90mm Width)



HMC441LP3E
Analog Devices, Inc
QFN-16



HMC948LP3E
Analog Devices, Inc
LP3



HMC358MS8GE Analog Devices, Inc MSOP-8



Analog Devices, Inc

**HMC490** 



HMC453ST89E
Analog Devices, Inc
ST89E



HMC618ALP3E
Analog Devices, Inc
QFN-16